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Synthesis and Characterization of the Ferrio-Substituted Silicon(II) Compound Me₅C₅(CO)₂FeSiC₅Me₅[†]

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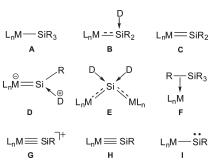
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Summary: Reaction of the (pentamethylcyclopentadienyl)-silicon cation with the (pentamethylcyclopentadienyl)dicarbonylferrate anion leads to the formation of the crystalline, thermolabile silicon(II) compound $[(\eta^5-pentamethylcyclopentadienyl)dicarbonylferrio](\eta^3-pentamethylcyclopentadienyl)-silicon. The singlet—triplet energy difference <math>\Delta E_{ST}$ is calculated to be 25.4 kcal/mol.

During the last few decades, several types of molecules containing transition-metal-silicon bonds have been synthesized and structurally characterized, including compounds of the type **A**–**H** in Chart 1, which contain single, ¹ double, ^{1,2} triple, ^{1,4} and electron-deficient bonds ^{1,5} between the transitionmetal fragment ML_n and a silicon atom and in which silicon is present in different formal oxidation states. 1,6 Some of these species are regarded to be important intermediates in metalcatalyzed reactions in organosilicon chemistry. Only very recently the first stable neutral compound of type H containing a metal-silicon triple bond, the molybdenum silylidyne complex $Cp(CO)_2MoSiC_6H_3-2,6-Trip_2$ (Trip = 2,4,6-triisopropylphenyl), has been synthesized. Interestingly, compounds of the type I, in which a transition-metal fragment is a substituent of a divalent silicon atom ("metallosilicon(II) compounds") are still unknown. The synthesis of a precursor molecule suitable for the preparation of the compound (H₅C₅)(CO)₂FeSiMe has already been described by West et al., but only trapping reactions could be performed successfully. Here, we report the synthesis, the X-ray crystal structure, some NMR data, and calculations of

Chart 1. Classes of Compounds Containing a Transition-Metal—Silicon Bond^a



 a Legend: $L_{n}M$ = transition-metal fragment; R = monofunctional group; D = donor molecule.

the first member in this class. For the RSi component, we have chosen the (pentamethylcyclopentadienyl)silicon ((Me $_5$ C $_5$)Si) unit. With the advent of the (pentamethylcyclopentadienyl)silicon cation, Me $_5$ C $_5$ Si $^+$, a novel route to neutral divalent silicon compounds is available, simply by the addition of anionic nucleophiles, as already shown by some examples. ^{8,9} For the anionic transition-metal component, we have chosen the (pentamethylcyclopentadienyl)dicarbonylferrate anion, due to the stabilizing effects of the Me $_5$ C $_5$ (CO) $_2$ Fe fragment exerted in comparable bonding situations. ¹⁰

The salt $[Me_5C_5Si]^+[B(C_6F_5)_4]^-$ (1) was reacted with the salt $Na^+[Fe(CO)_2C_5Me_5]^-$ (2) at -78 °C in two different solvents (see Scheme 1). In a mixture of dimethoxyethane and hexane, single-electron transfer (SET) took place exclusively to give the known Fe–Fe dimer $[Me_5C_5(CO)_2Fe]_2$ (3), 11 decamethylsilicocene (4), 12 and elemental silicon, the last two species presumably as the result of a disproportionation of a reactive intermediate of the composition $[Me_5C_5Si]_2$. 13 In hexane as solvent and in the

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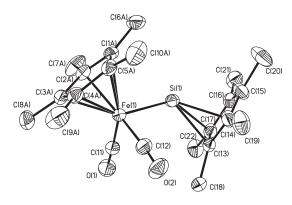


Figure 1. ORTEP plot of the molecular structure of **5**. Thermal ellipsoids represent 50% probability. Hydrogen atoms are omitted for clarity; the disorder at the (Fe)Cp* group is not shown (see the Supporting Information).

Scheme 1. Synthesis of the Ferriosilicon(II) Compound 5

presence of small amounts of diethyl ether, the title compound 5 was obtained in 48% yield after filtration and concentration of the remaining solution and after crystallization at $-30\,^{\circ}\text{C}$ as air-sensitive, brown crystals. In addition to compound 5, small amounts (\sim 3%) of the compounds 3 and 4 were detected by NMR spectroscopy in the remaining solution. In the solid state, compound 5 is stable at $-30\,^{\circ}\text{C}$ for some weeks; at ambient temperature it rearranges to the insertion product 6 (vide infra). In solution it decomposes mainly to 6, 3, and 4, as shown by NMR spectroscopy.

Despite the thermal instability of **5**, crystals could be grown from hexane solution at lower temperatures. The molecular structure was determined by single-crystal X-ray diffraction (Figure 1).¹⁴ The structure analysis shows the presence of a monomeric species with two Me₅C₅ (Cp*) ligands, one η^5 -bonded to iron and the other η^3 -bonded to silicon. The Si–C distances of 2.136(2) (Si–C(13)), 2.210(2) (Si–C(14)), and 2.435(2) Å (Si–C(17)) in the latter correspond to an asymmetric η^3 bonding. This bonding situation

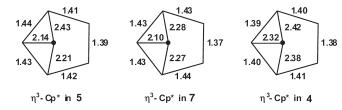
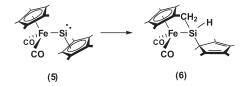


Figure 2. Si—C and C—C bond lengths in the $(\eta^3$ -Cp*)Si unit of compounds 5, 7, and 4.

Scheme 2. Rearrangement of 5 to 6



is comparable to that found in the arylsilicon(II) compound $[2,6-(\text{Trip})_2\text{H}_3\text{C}_6](\eta^3-\text{Cp*})\text{Si} (\text{Trip} = 2,4,6-i\text{Pr}_3\text{C}_6\text{H}_2) (7)^{15}$ and in the η^3 -Cp* unit in the sandwich compound Cp*₂Si (4) (see Figure 2). Thus, electron donation to the vacant orbital at silicon originates mainly from the Cp* ring. As expected, the Fe-Si bond length of 2.3677(6) Å in 5 is greater than that in the silicon(IV) compound Cp*(CO)₂FeSiH₃ (2.287(2) Å). ¹⁶ Thus, this bond is regarded to be rather weak (see below for the calculations). The angle at silicon (Fe-Si-C(13)) is 112.8(1)° and differs from the respective angle in the arylsilicon compound 7 (101.98(7)°). The geometry at the silicon atom may be qualitatively described on the basis of sp² hybridization, with one hybrid orbital representing the lone pair and the others engaged in bonding to the substituents. The remaining vacant p orbital at silicon interacts mainly with a filled π orbital at the Cp* fragment.

The ¹H NMR spectrum of **5** is in accord with the constitution of the compound as derived from the X-ray crystal structure data. It shows sharp singlets for both the iron-bonded and the silicon-bonded pentamethylcyclopentadienyl (Cp*) groups; the latter is slightly broadened on cooling to -50 °C, characteristic for the presence of a fluxional Cp* system. Similarly, the ¹³C NMR spectrum shows singlets for the ring carbon atoms and for the methyl groups both on the iron and on the siliconbonded Cp* group. In addition, a resonance signal for the CO groups is observed. The simplicity of the NMR spectra indicates the presence of a rather symmetric structure also in solution with a mirror plane along the Cp*(centroid)-Fe-Si-Cp*-(centroid) vector. In the ²⁹Si NMR spectrum, the resonance signal for the divalent silicon atom is observed at $\delta + 316.7$ ppm. Thus, a downfield shift of 716.8 ppm takes place on going from 1 (-400.1 ppm) to 5.

The silicon(II) compound **5** rearranges easily to the silicon(IV) compound **6** by oxidative addition of a C-H unit from the Cp* group at iron to the divalent silicon atom (see Scheme 2). The silicon(IV) compound **6** is characterized by a prochiral silicon atom and thus by several signals for the Cp* group at silicon in the 1 H and 13 C NMR spectra (see theExperimental Section). The 29 Si NMR signal of **6** is observed at δ –53.2 ppm with 1 J(SiH) = 205.4 Hz.

⁽¹⁴⁾ X-ray crystallography: single crystals of 5 were coated with a layer of hydrocarbon oil, attached to a glass fiber, and cooled to 100 K for data collection. Crystallographic data were collected with a Bruker Nonius KappaCCD diffractometer with Mo Kα radiation (graphite monochromator, $\lambda = 0.71073$ Å). Crystal data are as follows: $C_{22}H_{30}$ -FeO₂Si; $M_{\rm r}=410.40$; orthorhombic; *Pbca* (No. 61); a=15.1433(7) Å; b=9.2167(4) Å; c=30.8421(15) Å; V=4304.7(3) Å; V=4304.7(3reflections with $I > 2\sigma(I)$, wR2 = 0.1144 for all 6218 unique reflections, 268 parameters. Crystallographic programs used for structure solution and refinement were from SHELX-97. The structure was solved by direct methods and was refined by using full-matrix least squares on \vec{F} of all unique reflections with anisotropic thermal parameters for all nonhydrogen atoms, except the disordered carbons with 0.16 occupancy. The Cp* ring is disordered on two positions (84:16). Hydrogen atoms were included at calculated positions with $U(H) = 1.5 U_{eq}$ of the corresponding carbon atom. CCDC 774453 contains the supplementary crystallographic data for this paper. These data can be obtained free of charge from The Cambridge Crystallographic Data Centre via www. ccdc.cam.ac.uk/data_request/cif.

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To get a deeper insight into the structure and bonding of 5, calculations have been performed at a DFT level of theory. The calculated equilibrium structure (RI-BP86/TZVP) is comparable to that found by X-ray crystallography and is presented in the Supporting Information together with the x,y,z atom coordinates. All investigated structures are ensured as energy minima on the electronic hypersurface by corresponding vibrational analyses. The structure 5 shows the expected symmetry (mirror plane) with a η^5 -Cp* iron unit and with a η^3 -Cp* silicon unit, the latter with Si-C distances of 2.165 (Si-C(1)), 2.344 (Si-C(2)), and 2.353 Å (Si-C(2')). The Fe-Si bond length is found to be 2.378 Å, and the Fe-Si- C_1 angle is calculated to be 113.2°. Calculated structural parameters of the insertion product 6 are provided in the Supporting Information. Compound 6 is calculated to be only 9.3 kcal/mol more stable (with ZPE correction) than compound 5 in its singlet state.

A population analysis, based on the NBO values and on the Wiberg bond indices, implicates that the bonding in 5 is best described as a resonance hybrid between the ferriosilicon(II) species Cp*(CO)₂Fe-SiCp* and the donor-acceptor complex $[Cp^*(CO)_2Fe]^- \rightarrow [SiCp^*]^+$, resulting in a weak (Wiberg bond order of 0.541) Fe-Si bond. The latter is mainly located (74.2%) at Fe (23.2% s, 76.5% d) and less (25.8%) at Si (4.9% s, 94.8% p), supporting the donor-acceptor formulation. Following the population analysis, a charge of +0.216 is remaining on the half-sandwich fragment Me₅C₅Si. For the η^3 -Cp*-Si interaction, the Wiberg bond order indices are as follows: Si-C(1), 0.353; Si-C(2), 0.262; Si-C(2'), 0.259; Si-C(3), 0.070; Si-C(3'), 0.068. In addition to the calculated Cp*-Si π interaction, a rather weak Fe-Si π interaction is also conceivable, following arguments from MO theory. ¹⁸ This π contribution, involving the silicon-based p orbital and the Cp*(CO)₂Fe HOMO of a" symmetry, is substantiated in a lower molecular orbital (HOMO-4). The HOMO (σ orbital at silicon) and the LUMO (p orbital at silicon) are mainly localized at the silicon atom and thus reveal the nature of a silylene (for a full detail of the orbitals, see the Supporting Information).

The 29 Si NMR shift of **5** was calculated to be +295.5 ppm at the RI-BP86/TZVP level and +387.8 ppm at the B3LYP/TZVP level. The differences from the experimental value (+316.7 ppm)can be explained by strong paramagnetic contributions, which generally are not sufficiently recognized in calculations of this type. A strong paramagnetic contribution to the ²⁹Si NMR shift in the ground-state structure of 5 can be concluded from the calculated (adiabatic) singlet-triplet energy difference $\Delta E_{\rm ST}$ of 25.4 kcal/mol (ZPE included), which is not much larger than those calculated for SiH₂ ($\Delta E_{ST} = 16.6 \text{ kcal/mol}$)¹⁹ and SiMe₂ $(\Delta E_{\rm ST} = 23.0 \text{ kcal/mol}).$

The ferriosilicon(II) compound 5 might be a useful substrate for the preparation of a further species containing a metalsilicon triple bond.⁴ In germanium chemistry, the metallogermylene Cp(CO)₃MoGeC₆H₃(2,6-Mes₂) presumably has been a reactive intermediate in the preparation of the compound Cp(CO)₂MoGeC₆H₃(2,6-Mes₂), the first stable species containing a metal-germanium triple bond.²⁰ On the other hand, the ferriogermylenes CpFe(CO)₂GeCH-(SiMe₃)₂, CpFe(CO)₂GeMes*, and Cp*Fe(CO)₂GeMes* $(Mes^* = C_6H_2(2,4,6-tBu_3)^{21}$ could not be transformed into stable iron-germanium triple-bond systems.²²

Experimental Section. Synthesis of 5. Hexane (10 mL) and diethyl ether $(0.2 \,\mathrm{mL})$ were added at $-78 \,^{\circ}\mathrm{C}$ to a mixture of 1 (296 mg, 0.35 mmol) and 2 (95 mg, 0.35 mmol). The reaction mixture was stirred for 1 h at -78 °C and then warmed to -25 °C over 2 h and stirred for a further 3 h at -25 °C. At this temperature the resulting brown suspension was filtered. The remaining solid was extracted with cold hexane (5 mL). The combined hexane solutions were concentrated to ~1 mL and left to crystallize overnight at -30 °C. Compound 5 was isolated as brown crystals (69 mg, yield 48%). The remaining solution contained 5, contaminated with small amounts of 3 and 4, as checked by NMR spectroscopy.

Data for compound 5 are as follows. ¹H NMR (600.13 MHz, C_6D_6 , TMS external, δ (ppm)): 2.11 (Me_5C_5Si); 1.53 (Me_5C_5Fe). ¹³C NMR (250 MHz, in C_6D_6 , TMS internal, δ (ppm)): 9.2, 96.1 (Me₅C₅Fe), 10.9, 119.9 (Me₅C₅Si), 218.6 (CO). ²⁹Si NMR (119.23 MHz, in C_6D_6 , TMS external, δ (ppm)): +316.7.

 1 H NMR for compounds 3 and 4 (in $C_{6}D_{6}$, TMS internal, δ (ppm)): compound **3**, 1.59 (lit. 11 1.62 (CS₂)); compound **4**, 1.89 (identical with literature data¹²).

Compound 6. Compound 5 (32 mg) was stored for 1 week in a glovebox. A quantitative rearrangement to 6 (32 mg, orange solid) was observed.

Data for compound 6 are as follows. ¹H NMR (600.13 MHz, toluene- d_8 , 298 K, TMS external, δ (ppm)): 1.48, 1.54, 1.66, $1.72 (4 \text{ s}, Me_4C_5\text{Fe}), 1.90 (\text{s}, \text{br}, Me_5C_5\text{Si}), 1.84, 1.96 (2 \text{ dd}, {}^2J(\text{H},$ H) = 14.0 Hz, ${}^{3}J(H,H) = 4.4 \text{ Hz}$) (C $H_{2}Me_{4}C_{5}Fe$), $3.17 \text{ (t, } {}^{3}J(H,H) = 4.4 \text{ Hz}$) H) = 4.4 Hz) (Si-H). ¹H NMR (600.13 MHz, toluene- d_8 , 233 K, TMS external, δ (ppm)): 1.38, 1.89, 2.00, 2.04, 2.23 (5 s, Me₅C₅Si), 1.41,1.46, 1.60, 1.67 (4 s, Me₄C₅Fe), 1.86, 1.93 (2 dd, $^{2}J(H,H = 13.5 \text{ Hz}, ^{3}J(H,H) = 4.6 \text{ Hz}) (CH_{2}\text{Me}_{4}\text{C}_{5}\text{Fe}), 3.09 (s,$ br) (Si-H). 13 C NMR (150.90 MHz, toluene- d_8 , 233 K, TMS external, δ (ppm)): 11.6, 11.8, 12.0, 12.3, 14.1, 53.1, 134.7, 134.9, 138.4, 138.9 (Me₅C₅Si), 9.0, 10.0, 10.1, 10.2, 84.0, 85.5, 88.1, 99.3, 100.3 (Me₄C₅Fe), 4.8 (CH₂Si), 218.4, 219.8 (CO). ²⁹Si NMR (119.23 MHz, C_6D_6 , 298 K, TMS external, δ (ppm)): $-53.2 (^{1}J(Si,H) = 205.4 \text{ Hz}). \text{ IR (KBr pellet, cm}^{-1}): \nu(CO)$ 1967, 1913. HR MS (EI, m/z): calcd for $C_{22}H_{30}O_2FeSi$ 408.1411, found 408.1369.

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Supporting Information Available: Tables, figures, and a CIF file giving crystal structure data of 5, calculated geometries and energies of 5 (singlet and triplet) and of 6, and front orbitals (Kohn-Sham orbitals) for the singlet state of 5. This material is available free of charge via the Internet at http://pubs.acs.org.

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